NPN - 2N6515, 2N6517; PNP - 2N6520

High Voltage Transistors NPN and PNP

Features

- Voltage and Current are Negative for PNP Transistors
- These are Pb-Free Devices*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage 2N6515 2N6517, 2N6520	V _{CEO}	250 350	Vdc
Collector – Base Voltage 2N6515 2N6517, 2N6520	V _{CBO}	250 350	Vdc
Emitter – Base Voltage 2N6515, 2N6517 2N6520	V _{EBO}	6.0 5.0	Vdc
Base Current	I _B	250	mAdc
Collector Current – Continuous	Ic	500	mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _D	625 5.0	mW mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C

THERMAL CHARACTERISTICS

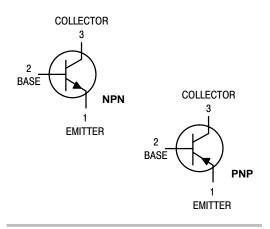
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	°C/W

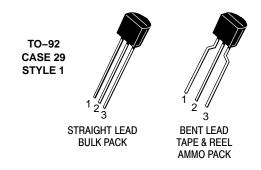
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



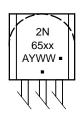
ON Semiconductor®

http://onsemi.com





MARKING DIAGRAM



xx = 15, 17, or 20

A = Assembly Location

Y = Year

WW = Work Week

■ = Pb–Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

^{*}For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

NPN - 2N6515, 2N6517; PNP - 2N6520

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

	Symbol	Min	Max	Unit
			I	
2N6515 2N6517, 2N6520	V _(BR) CEO	250 350	_ _	Vdc
2N6515 2N6517, 2N6520	V _{(BR)CBO}	250 350	_ _	Vdc
2N6515, 2N6517 2N6520	$V_{(BR)EBO}$	6.0 5.0	_ _	Vdc
2N6515 2N6517, 2N6520	I _{CBO}	_ _	50 50	nAdc
2N6515, 2N6517 2N6520	I _{EBO}	- -	50 50	nAdc
2N6515 2N6517, 2N6520	h _{FE}	35 20		-
2N6515 2N6517, 2N6520		50 30	- -	
2N6515 2N6517, 2N6520		50 30	300 200	
2N6515 2N6517, 2N6520		45 20	220 200	
2N6515 2N6517, 2N6520		25 15	- -	
	V _{CE(sat)}	- - - -	0.30 0.35 0.50 1.0	Vdc
	V _{BE(sat)}	- - -	0.75 0.85 0.90	Vdc
	V _{BE(on)}	-	2.0	Vdc
	f _T	40	200	MHz
	C _{cb}	-	6.0	pF
2N6515, 2N6517 2N6520	C _{eb}	<u>-</u>	80 100	pF
ide)	t _{on}	_	200	μS
	t _{off}	-	3.5	μS
	2N6517, 2N6520 2N6515 2N6517, 2N6520 2N6515, 2N6517 2N6520 2N6515, 2N6517 2N6520 2N6515, 2N6517 2N6520 2N6515 2N6517, 2N6520	2N6515 2N6517, 2N6520 2N6517, 2N6520 2N6517, 2N6520 2N6515, 2N6517 2N6520 2N6515, 2N6517 2N6520 2N6515, 2N6517 2N6520 2N6517, 2N6520 VCE(sat) VBE(on) Adc) V(BR)CBO CBO CO CO CO CO CO CO CO CO	2N6515, 2N6515 2N6517, 2N6520 2N6515, 2N6517 2N6520 2N6515, 2N6515 2N6517, 2N6520 2N6515, 2N6520 2N6515, 2N6515 2N6517, 2N6520 2N6515, 2N6515 2N6517, 2N6520 2N6515 2N6517 2N6520 VCE(sat) VBE(on) - VBE(on) - - - - - - - - - - - - -	2N6515

^{1.} Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%.

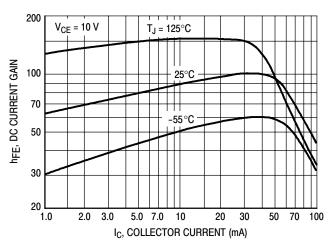


Figure 1. DC Current Gain NPN 2N6515

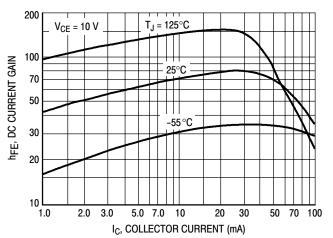


Figure 2. DC Current Gain NPN 2N6517

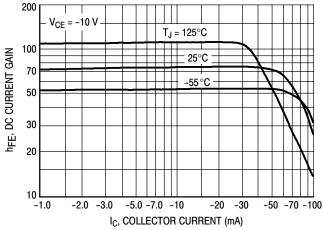


Figure 3. DC Current Gain PNP 2N6520

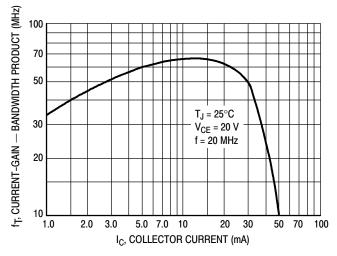


Figure 4. Current-Gain - Bandwidth Product NPN 2N6515, 2N6517

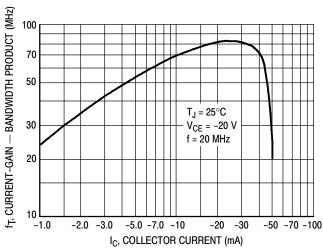


Figure 5. Current–Gain – Bandwidth Product PNP 2N6520

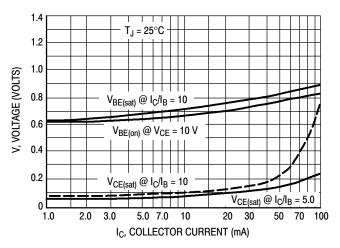


Figure 6. "On" Voltages NPN 2N6515, 2N6517

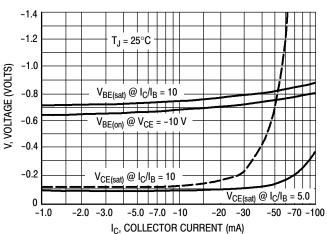


Figure 7. "On" Voltages PNP 2N6520

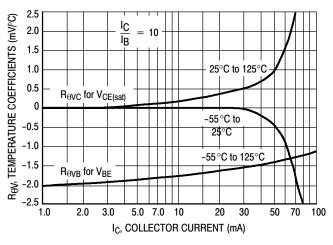


Figure 8. Temperature Coefficients NPN 2N6515, 2N6517

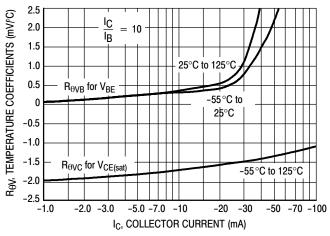


Figure 9. Temperature Coefficients PNP 2N6520

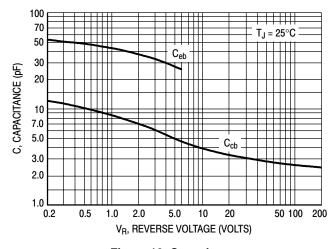


Figure 10. Capacitance NPN 2N6515, 2N6517

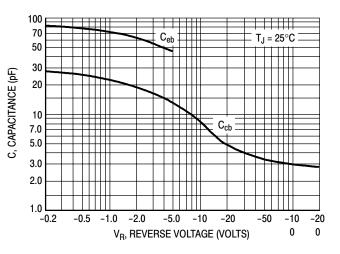
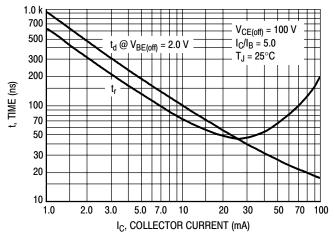


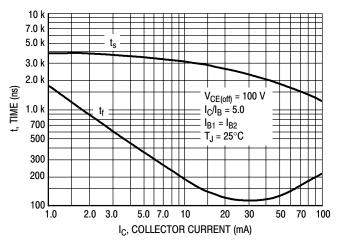
Figure 11. Capacitance PNP 2N6520



1.0 k 700 $V_{CE(off)} = -100 \text{ V}$ $t_d @ V_{BE(off)} = 2.0 V$ 500 $I_{C}/I_{B} = 5.0$ $T_J=25^{\circ}C$ 300 200 t, TIME (100 70 50 30 20 10 -1.0 -5.0 -7.0 -10 -50 -70 -100 I_C, COLLECTOR CURRENT (mA)

Figure 12. Turn-On Time NPN 2N6515, 2N6517

Figure 13. Turn-On Time PNP 2N6520



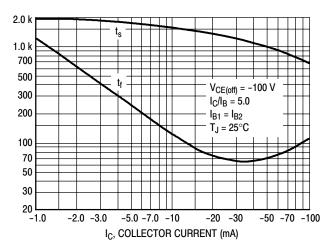


Figure 14. Turn-Off Time NPN 2N6515, 2N6517

Figure 15. Turn-Off Time PNP 2N6520

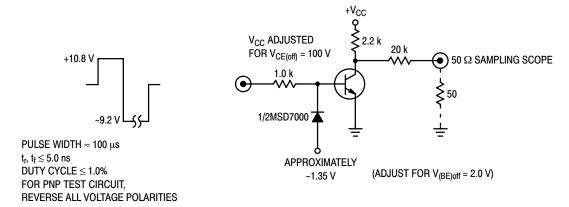


Figure 16. Switching Time Test Circuit

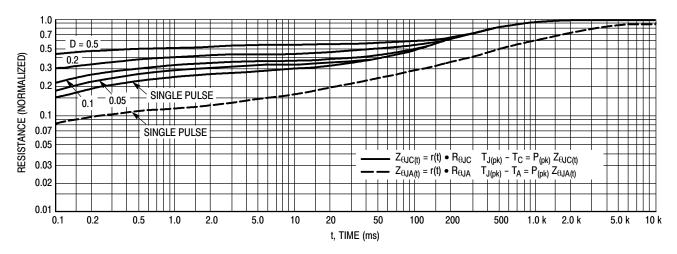


Figure 17. Thermal Response

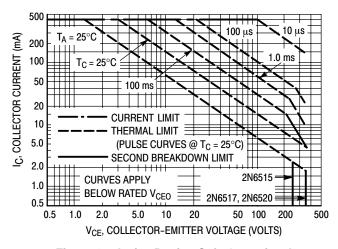
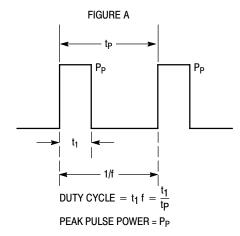


Figure 18. Active Region Safe Operating Area



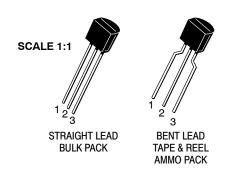
Design Note: Use of Transient Thermal Resistance Data

ORDERING INFORMATION

Device	Package	Shipping [†]
2N6515RLRMG	TO-92 (Pb-Free)	2000 Ammo Pack
2N6517G	TO-92 (Pb-Free)	5000 Unit / Bulk
2N6517RLRPG	TO-92 (Pb-Free)	2000 Ammo Pack
2N6520RLRAG	TO-92 (Pb-Free)	2000 Tape & Reel

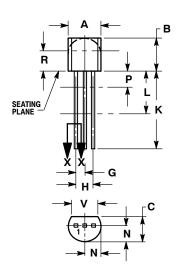
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.





TO-92 (TO-226) CASE 29-11 **ISSUE AM**

DATE 09 MAR 2007

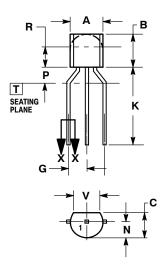


STRAIGHT LEAD **BULK PACK**



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
 4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
P		0.100		2.54
R	0.115		2.93	
٧	0.135		3.43	



BENT LEAD TAPE & REEL AMMO PACK



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
 4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	MILLIMETERS				
DIM	MIN	MAX			
Α	4.45	5.20			
В	4.32	5.33			
С	3.18	4.19			
D	0.40	0.54			
G	2.40	2.80			
J	0.39	0.50			
K	12.70				
N	2.04	2.66			
P	1.50	4.00			
R	2.93				
V	3.43				

STYLES ON PAGE 2

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DATE 09 MAR 2007

STYLE 1: PIN 1. 2. 3.	EMITTER BASE COLLECTOR	STYLE 2: PIN 1. 2. 3.	BASE EMITTER COLLECTOR	STYLE 3: PIN 1. 2. 3.	ANODE ANODE CATHODE	STYLE 4: PIN 1. 2. 3.	CATHODE CATHODE ANODE	STYLE 5: PIN 1. 2. 3.	DRAIN
2.	GATE SOURCE & SUBSTRATE DRAIN	STYLE 7: PIN 1. 2. 3.	SOURCE DRAIN GATE	STYLE 8: PIN 1. 2. 3.	DRAIN GATE SOURCE & SUBSTRATE	PIN 1.	BASE 1		CATHODE
2.	ANODE CATHODE & ANODE CATHODE	STYLE 12: PIN 1. 2. 3.	MAIN TERMINAL 1 GATE MAIN TERMINAL 2	PIN 1.	ANODE 1	PIN 1.	EMITTER COLLECTOR BASE	PIN 1. 2.	
2.	ANODE GATE	PIN 1. 2.	COLLECTOR BASE	PIN 1. 2.	ANODE CATHODE	PIN 1. 2.	GATE	2.	NOT CONNECTED
2.	COLLECTOR	PIN 1. 2.	SOURCE GATE DRAIN	STYLE 23: PIN 1. 2. 3.	GATE SOURCE DRAIN	STYLE 24: PIN 1. 2. 3.	EMITTER COLLECTOR/ANODE CATHODE	STYLE 25: PIN 1. 2. 3.	MT 1 GATE
	V _{CC}	PIN 1. 2.	MT	STYLE 28: PIN 1. 2.	CATHODE ANODE GATE	STYLE 29: PIN 1. 2.		PIN 1. 2.	DRAIN
	GATE	PIN 1. 2.		STYLE 33: PIN 1. 2. 3.	RETURN	2.			

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